

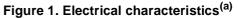
STPS3L45AF

Power Schottky rectifier

Datasheet - production data



Schottky rectifier suited for switched mode power supplies and high frequency DC to DC converters. Packaged in a tiny SMAflat package, this device has been optimized for use in compact chargers.



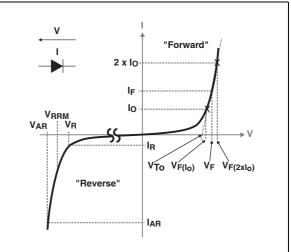
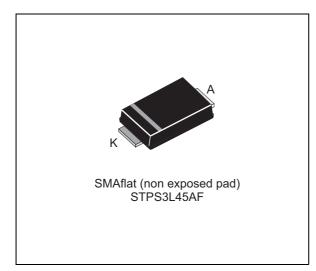


Table 1. Device summary

Symbol	value
I _{F(AV)}	3 A
V _{RRM}	45 V
T _j (max)	150 °C
V _F (typ)	0.462 V



Features

- Negligible switching losses
- Low thermal resistance
- Low forward voltage drop
- Avalanche capability specified

February 2014

a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 11*. V_{AR} and I_{AR} are pulse measurements ($t_p < 10 \ \mu$ s). V_R, I_R, V_{RRM} and V_F, are static characteristics

1 Characteristics

Symbol	Parameter	Test conditions	Value	Unit
V _{RRM}	Repetitive peak reverse voltage		45	V
I _{F(AV)}	Average forward current	$T_{L} = 120 \ ^{\circ}C \ \delta = 0.5$	3	А
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	75	А
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power	t _p = 10 μs Tj = 125 °C	70	W
V _{ARM} ⁽²⁾ Maximum repetitive peak avalanche voltage		t _p < 10 μs, Tj < 125 °C, I _{AR} < 1.4 A	50	V
V _{ASM} ⁽²⁾	Maximum single pulse peak avalanche voltage	$t_p < 10 \ \mu s$, Tj < 125 °C, I _{AR} < 1.4 A	50	V
T _{stg}	Storage temperature range		-65 to + 175	°C
Тj	Operating junction temperature ⁽³⁾		150	°C

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

 For pulse time duration deratings, please refer to *Figure 4*. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics Application notes AN1768, "Admissible avalanche power of Schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

2. Refer to *Figure 11*

3. $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter		Unit
R _{th(j-l)}	Thermal resistance junction to lead	15	°C/W

Symbol **Test conditions** Unit Parameter Тур. Max. T_i = 25 °C 300 80 μA $I_{R}^{(1)}$ Reverse leakage current $V_R = V_{RRM}$ T_i = 125 °C 66 135 mΑ T_i = 25 °C 0.462 0.57 $V_{F}^{(1)}$ V Forward voltage drop $I_F = 3 A$ = 125 °C 0.41 0.51 Ti

Table 4. Static electrical characteristics

1. Pulse test: $t_p = 380 \ \mu s$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 0.36 \times I_{F(AV)} + 0.05 I_{F}^{2}(RMS)$



Figure 2. Average forward power dissipation versus average forward current

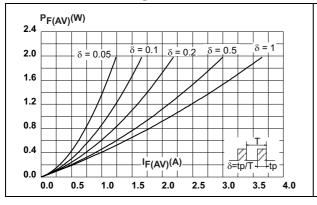


Figure 4. Normalized avalanche power derating versus pulse duration

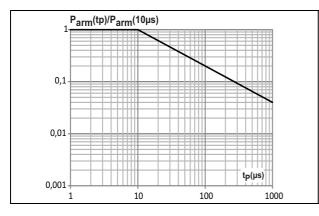


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$)

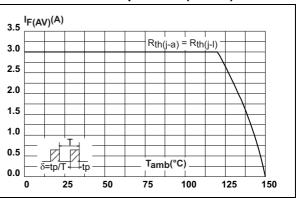


Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration

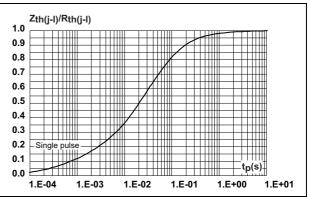
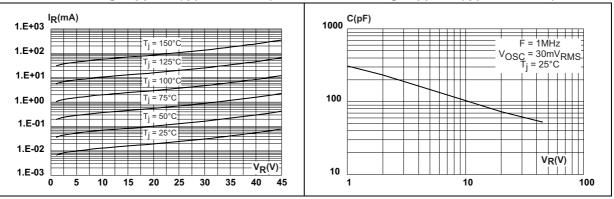


Figure 7. Junction capacitance versus reverse voltage applied (typical values)





current (typical values)

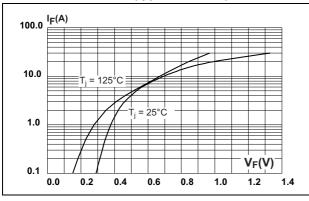


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values)



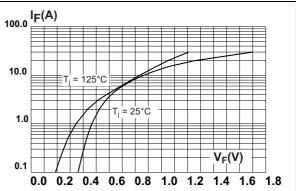
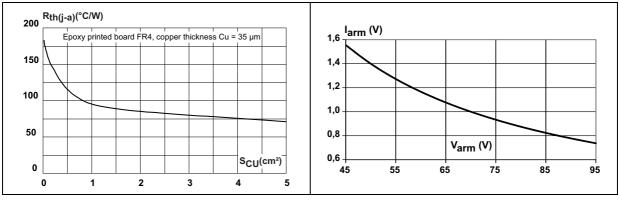


Figure 11. Reverse safe operating area (t_p < 10 μ s and T_j < 125 °C)





2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

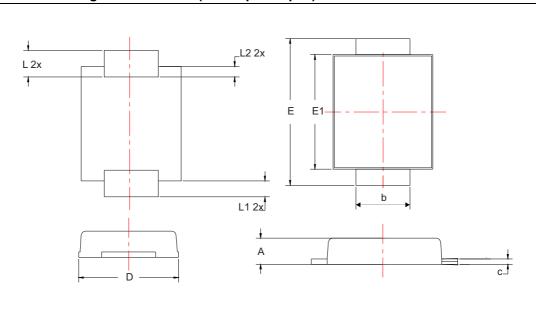


Figure 12. SMAflat (non-exposed pad) dimension definitions

Table 5. SMAflat (non-exp	osed pad) dimension values
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	Dimensions					
Ref.	Millimeters				Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.90		1.10	0.035		0.043
b	1.25		1.65	0.049		0.065
с	0.15		0.40	0.006		0.016
D	2.25		2.95	0.088		0.116
E	4.80		5.60	0.189		0.220
E1	3.95		4.60	0.155		0.181
L	0.75		1.50	0.029		0.059
L1		0.50			0.020	
L2		0.50			0.020	



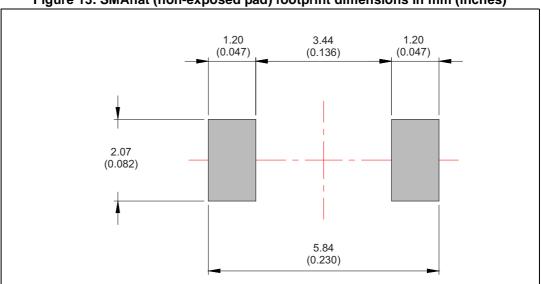


Figure 13. SMAflat (non-exposed pad) footprint dimensions in mm (inches)



3 Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3L45AF	F3L45	SMAflat (non-exposed pad)	0.035 g	10000	Tape and reel

4 Revision history

Table 7. Document revision histor

Date	Revision	Description of changes	
08-Jul-2013	1	First release.	
03-Feb-2014	2	Updated Table 5, Figure 12 and Figure 13.	



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DocID024949 Rev 2

